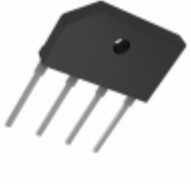
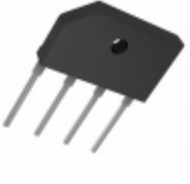
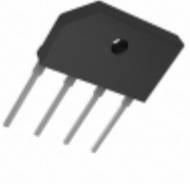


  Image may be representation. See specs for product details.	KBJ410G
	Hersteller-Teilenummer: KBJ410G
	Hersteller / Marke: GeneSiC Semiconductor
	Teil der Beschreibung: DIODE BRIDGE 1000V 4A KBJ
	Datenblätter:  1.KBJ410G.pdf  2.KBJ410G.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 2617 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	KBJ410G
Hersteller	GeneSiC Semiconductor
Beschreibung	DIODE BRIDGE 1000V 4A KBJ
Kategorie	Diskrete Halbleiterprodukte > Dioden-Brücke-
Teilstatus	2617 pcs Stock
Spannung - Spitzensperr- (max)	1000V
Spannung - Forward (Vf) (Max) @ If	1.1V @ 4A
Technologie	Standard
Supplier Device-Gehäuse	KBJ
Serie	-
Verpackung	Bulk
Verpackung / Gehäuse	4-SIP, KBJ
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Diodentyp	Single Phase
Strom - Sperrleckstrom @ Vr	5µA @ 1000V
Strom - Richt (Io)	4A

Sie können auch interessiert

sein:  KBJ408G Diodes Incorporated RECT BRIDGE GPP 4A 800V KBJ	 KBJ4J DEC DEC ZIP-4	 KBJ410 HY KBJ410 HY	 KBJ408G-TU LITEON LITEON DIP
 KBJ6005G Diodes Incorporated RECT BRIDGE GPP 6A 50V KBJ	 KBJ410G Diodes Incorporated RECT BRIDGE GPP 4A 1000V KBJ	 KBJ601G Diodes Incorporated RECTIFIER BRIDGE GPP 100V 6A KBJ	 KBJ4KV N/A N/A TO220

KBJ410G Zugehöriges

Mehr

KBJ410G Schlüsselwort	KBJ410G Datenblatt	KBJ410G-Datenblätter	KBJ410G PDF	GeneSiC Semiconductor KBJ410G
KBJ410G Electronic	KBJ410G-Komponenten	KBJ410G-Verteiler	KBJ410G-Bild	KBJ410G-Teil
KBJ410G Preis	KBJ410G Hersteller	KBJ410G Bild	KBJ410G Aktie	KBJ410G Inventar
KBJ410G Neu	KBJ410G Original	KBJ410G garantiert	KBJ410G RFQ	KBJ410G Online bestellen